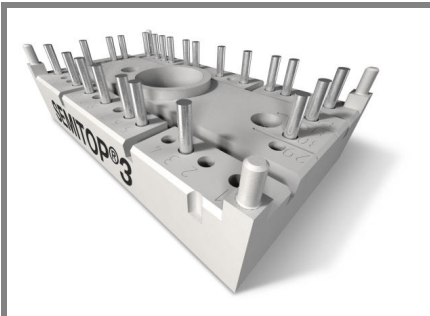


# SK 25 DGD 065 ET



**SEMITOP<sup>®</sup> 3**

**3-phase bridge rectifier +  
3-phase bridge inverter**

**SK 25 DGD 065 ET**

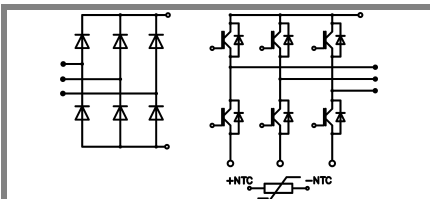
Preliminary Data

## Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminum oxide ceramic (DCB)
- Ultrafast NPT technology IGBT
- CAL Technology FWD
- Integrated NTC temperature sensor

## Typical Applications\*

- Inverter



**DGD - ET**

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Inverter, Chopper</b>			
$V_{CES}$		600	V
$I_C$	$T_s = 25$ (80) $^\circ\text{C}$	30 (22)	A
$I_{CRM}$	$I_{CRM} = 2 \times I_{Cnom}$ , $t_p = 1$ ms	60	A
$V_{GES}$		$\pm 20$	V
$T_j$		-40 ... +150	$^\circ\text{C}$
<b>Diode - Inverter, Chopper</b>			
$I_F$	$T_s = 25$ (80) $^\circ\text{C}$	36 (24)	A
$I_{FRM}$	$I_{FRM} = 2 \times I_{Fnom}$ , $t_p = 1$ ms	70	A
$T_j$		-40 ... +150	$^\circ\text{C}$
<b>Rectifier</b>			
$V_{RRM}$		800	V
$I_F$	$T_s = 80$ $^\circ\text{C}$	35	A
$I_{FSM} / I_{TSM}$	$t_p = 10$ ms, $\sin 180^\circ$ , $T_j = 25$ $^\circ\text{C}$	370	A
$I_t^2$	$t_p = 10$ ms, $\sin 180^\circ$ , $T_j = 25$ $^\circ\text{C}$	685	$\text{A}^2\text{s}$
$T_j$		-40 ... +150	$^\circ\text{C}$
$T_{sol}$	Terminals, 10s	260	$^\circ\text{C}$
$T_{stg}$		-40 ... +125	$^\circ\text{C}$
$V_{isol}$	AC, 1 min. / 1s	2500 / 3000	V

Characteristics		$T_s = 25^\circ\text{C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Inverter, Chopper</b>					
$V_{CEsat}$	$I_C = 20$ A, $T_j = 25$ (125) $^\circ\text{C}$		1,8 (2,1)	2 (2,2)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 0,5$ mA	3	4	5	V
$V_{CE(TO)}$	$T_j = 25$ $^\circ\text{C}$ (125) $^\circ\text{C}$		1,2 (1,1)	1,3	V
$r_T$	$T_j = 25$ $^\circ\text{C}$ (125) $^\circ\text{C}$		40 (55)	60	m $\Omega$
$C_{ies}$	$V_{CE} = V_{GE} = 0$ V, $f = 1$ MHz		1,6		nF
$C_{oes}$	$V_{CE} = V_{GE} = 0$ V, $f = 1$ MHz		-		nF
$C_{res}$	$V_{CE} = V_{GE} = 0$ V, $f = 1$ MHz		-		nF
$R_{th(j-s)}$	per IGBT			1,4	K/W
$t_{d(on)}$	under following conditions		30		ns
$t_r$	$V_{CC} = 300$ V, $V_{GE} = \pm 15$ V		25		ns
$t_{d(off)}$	$I_C = 25$ A, $T_j = 125$ $^\circ\text{C}$		250		ns
$t_f$	$R_{Gon} = R_{Goff} = 33$ $\Omega$		15		ns
$E_{on}$	inductive load		0,8		mJ
$E_{off}$			0,55		mJ
<b>Diode - Inverter, Chopper</b>					
$V_F = V_{EC}$	$I_F = 25$ A, $T_j = 25$ (125) $^\circ\text{C}$		1,45 (1,4)	1,7 (1,75)	V
$V_{(TO)}$	$T_j = 25$ $^\circ\text{C}$ (125) $^\circ\text{C}$		(0,85)	(0,9)	V
$r_T$	$T_j = 25$ $^\circ\text{C}$ (125) $^\circ\text{C}$		(22)	(32)	m $\Omega$
$R_{th(j-s)}$	per diode			1,7	K/W
$I_{RRM}$	under following conditions		-		A
$Q_{rr}$	$I_F = A$ , $V_R = V$		-		$\mu\text{C}$
$E_{rr}$	$V_{GE} = 0$ V, $T_j =$ $^\circ\text{C}$ $di_F/dt = - A/\mu\text{s}$		-		mJ
<b>Diode rectifier</b>					
$V_F$	$I_F = 15$ A, $T_j = 25$ ( $^\circ$ ) $^\circ\text{C}$		1,1		V
$V_{(TO)}$	$T_j = 150$ $^\circ\text{C}$		0,8		V
$r_T$	$T_j = 150$ $^\circ\text{C}$		15		m $\Omega$
$R_{th(j-s)}$	per diode			1,7	K/W
<b>Temperatur sensor</b>					
$R_{ts}$	5 %, $T_r = 25$ (100) $^\circ\text{C}$		5000(493)		$\Omega$
<b>Mechanical data</b>					
w			30		g
$M_s$	Mounting torque	2,3		2,5	Nm

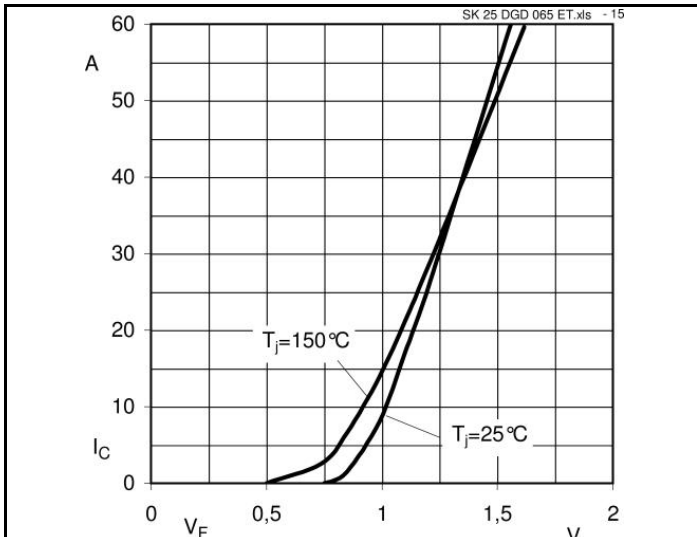


Fig. 15 Typ. Input Bridge Diode forward characteristic

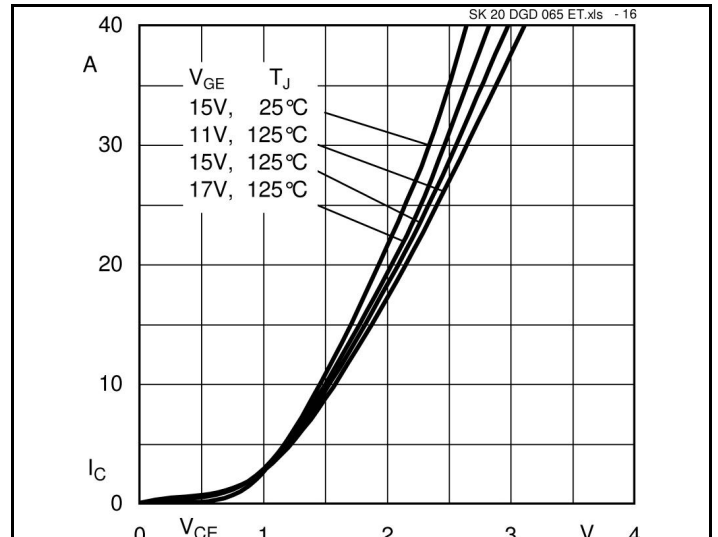


Fig. 16 Typical Output Characteristic

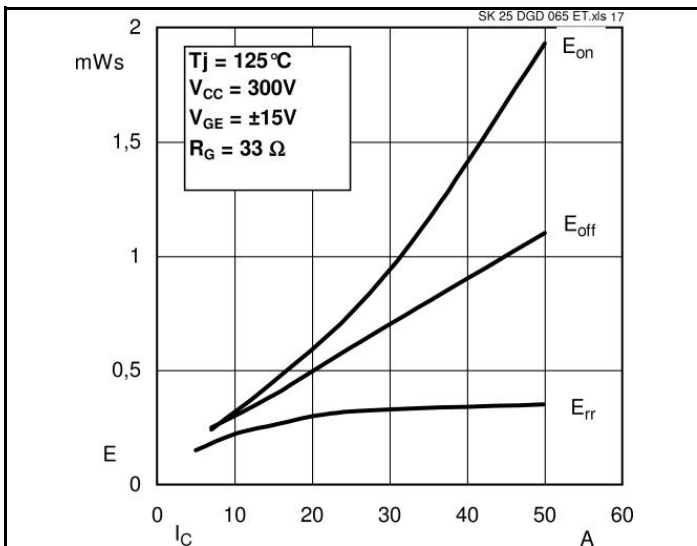


Fig. 17 Turn-On/Off Energy =  $f(I_C)$

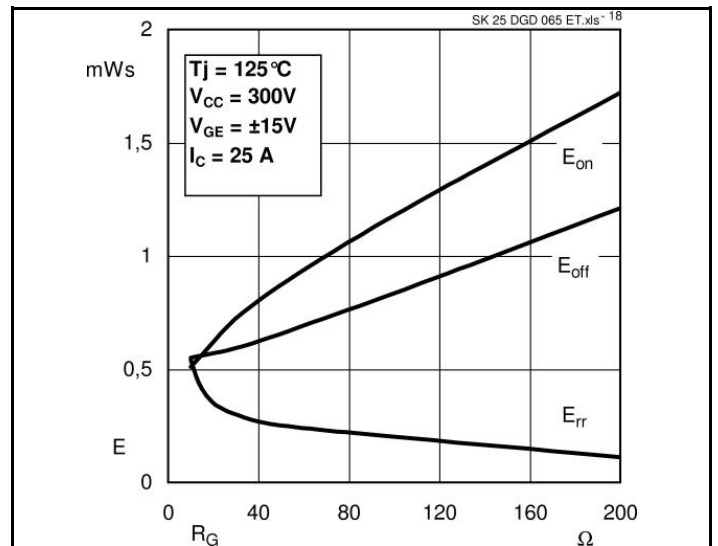


Fig. 18 Turn-On/Off Energy =  $f(R_G)$

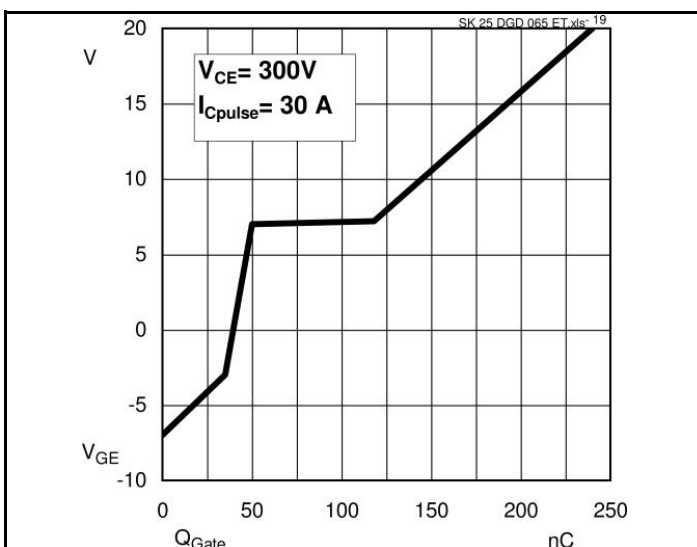


Fig. 19 Typical Gate Charge Characteristic

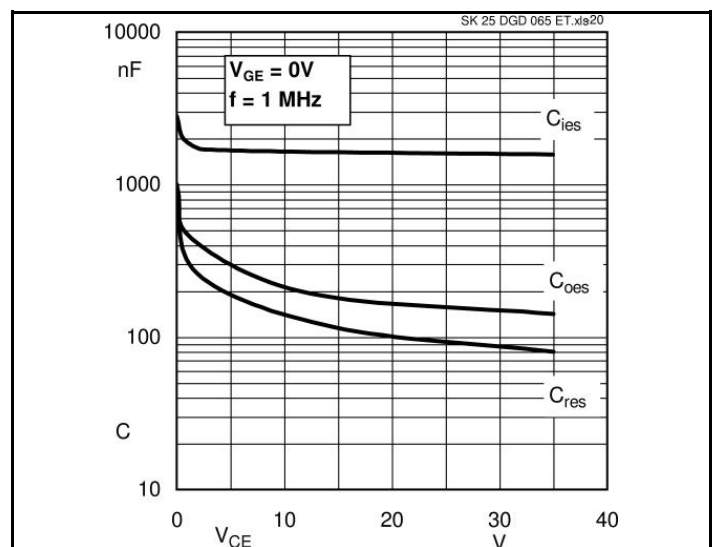
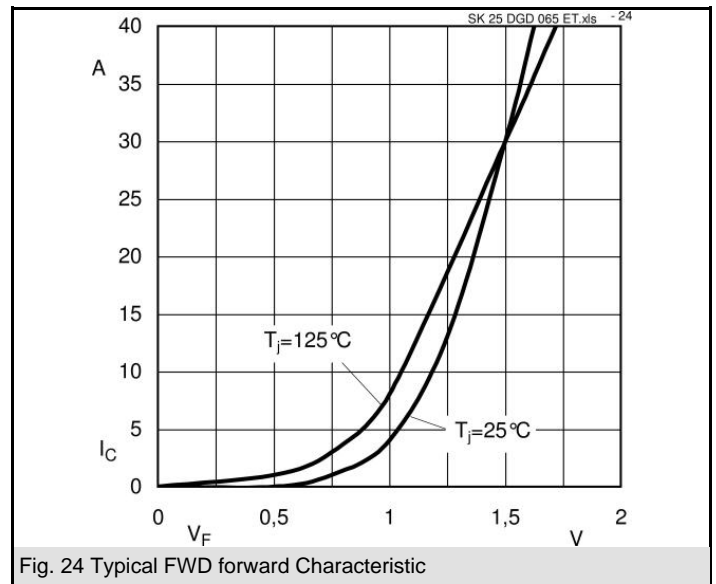
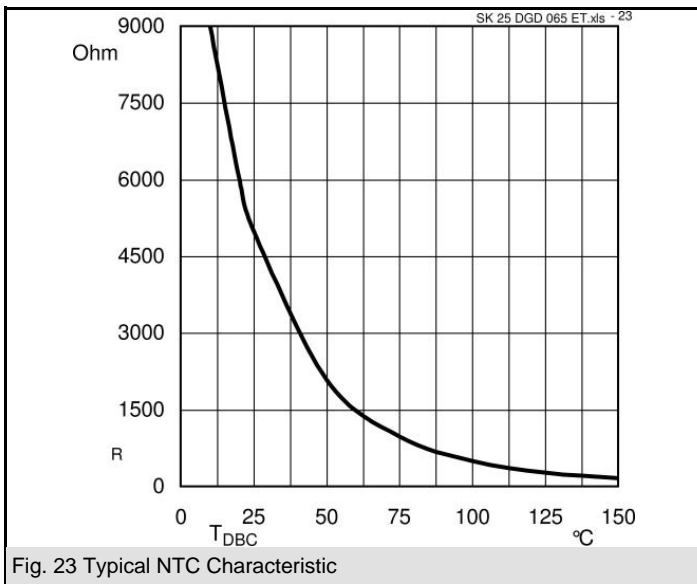
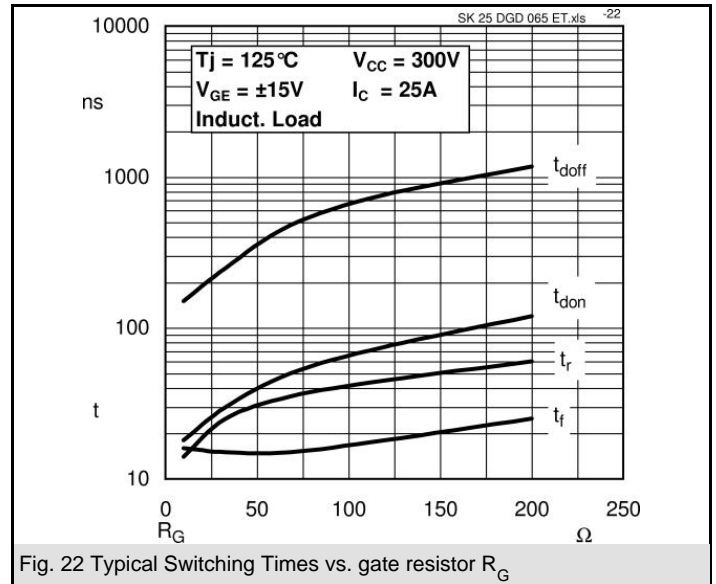
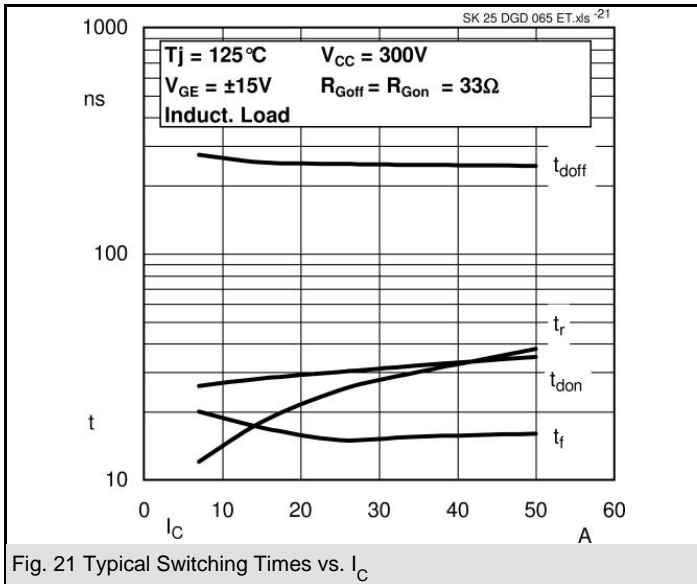
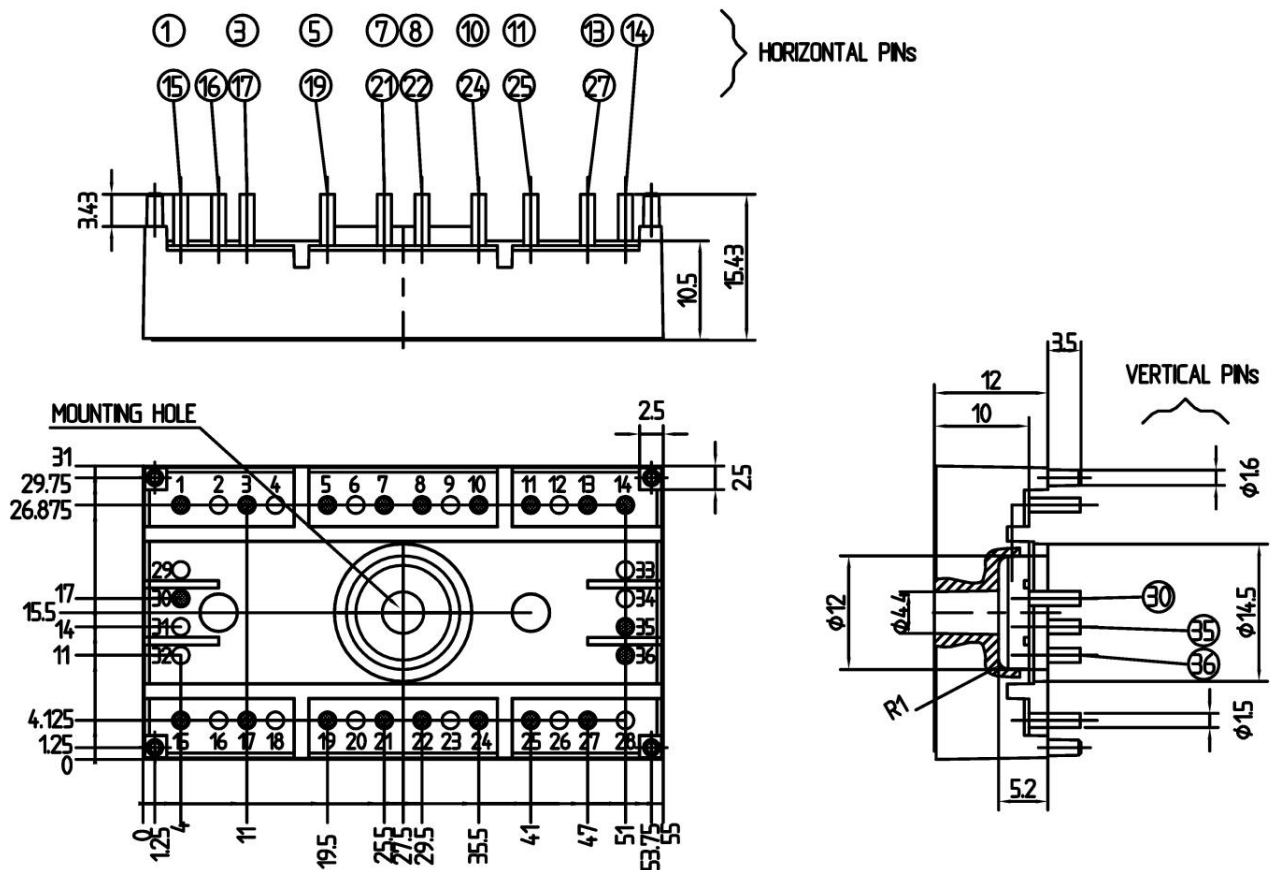
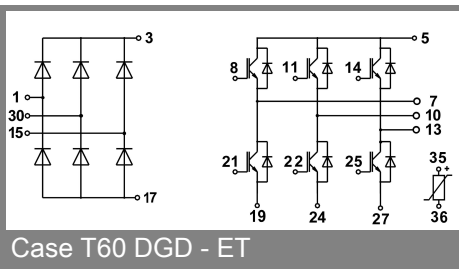


Fig. 20 Typical Capacitances vs.  $V_{CE}$





Case T60 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T60 DGD - ET

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.